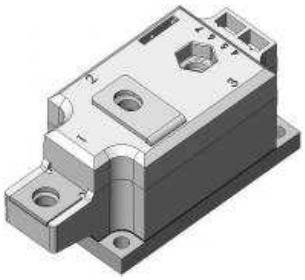
Rectifier Diode Modules
AMKE 380



V_{RSM} V	V_{RRM}, V_{DRM} V	I_{FRMS} = 930 A (maximum value for continuous operation) I_{FAV} = 600 A (sin. 180; T_C = 100°C)		
1300 1700	1200 1600	AMKE 380-12 AMKE 380-16		

Symbols and parameters			Values	Units
I_{FAV}	Mean forward current	sin 180; T_C = 100°C	380	A
I_{FSM}	Surge forward current	T_{vj} = 25°C; 10 ms T_{vj} = 150°C; 10 ms	11000 10000	A A
i^2t	I^2t value, rating for fusing	T_{vj} = 25°C; 8.3…10 ms T_{vj} = 150°C; 8.3…10 ms	605000 500000	A^2s A^2s
V_F	Forward voltage	T_{vj} = 25°C; I_F = 1000 A	max. 1.25	V
$V_{(TO)}$	On-state threshold voltage	T_{vj} = 150°C	max. 0.8	V
r_T	On-state slope resistance	T_{vj} = 150°C	max. 0.35	mΩ
I_{RD}	Direct reverse current	T_{vj} = 150°C; V_{RD} = V_{RRM}	max. 10	mA
$R_{th(j-c)}$	Thermal resistance, junction to case	cont.; per diode = per module sin.180; per diode = per module	0.11 0.116	K/W K/W
$R_{th(c-s)}$	Thermal resistance, junction to heatsink	per diode = per module	0.04	K/W
T_{vj}	(Virtual) junction temperature		-40 … +150	°C
T_{stg}	Storage temperature range		-40 … +130	°C
V_{isol}	Insulation test voltage (r.m.s.)	a.c. 50 Hz; r.m.s.; 1s / 1min.	3600 / 3000	V~
M_S	Mounting torque on heatsink		5 ± 15%	Nm
M_t	Mounting torque for terminals		9± 15%	Nm
a	Maximum allowable acceleration		5*9.81	m/s^2
W	Weight		550	g

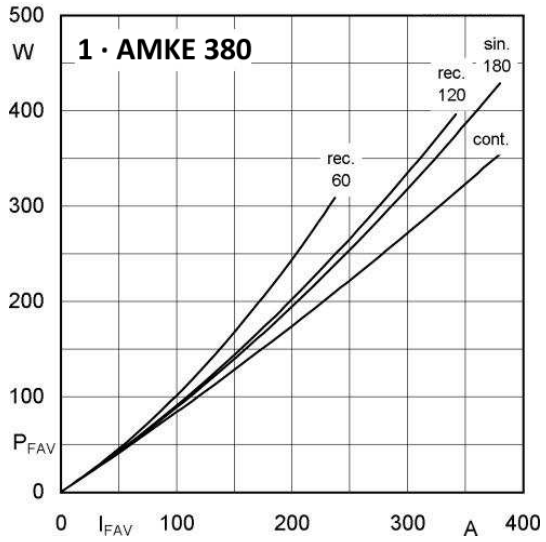


Fig. 11L Power dissipation per diode vs. forward current

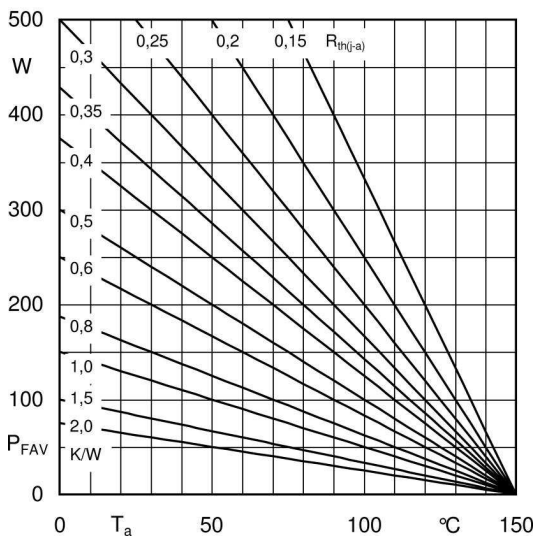


Fig. 11R Power dissipation per diode vs. ambient temperature

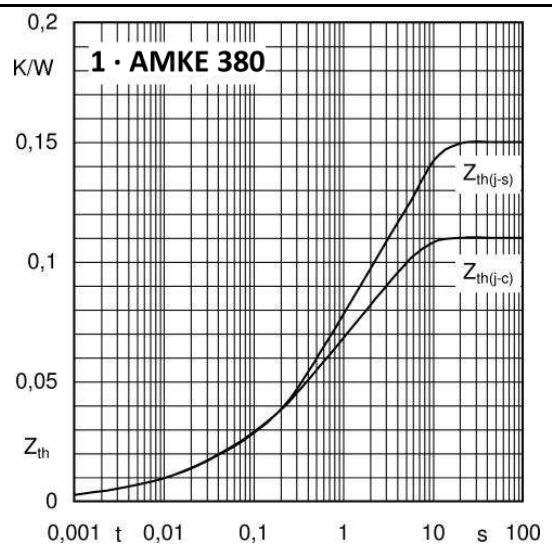


Fig. 14 Transient thermal impedance vs. time

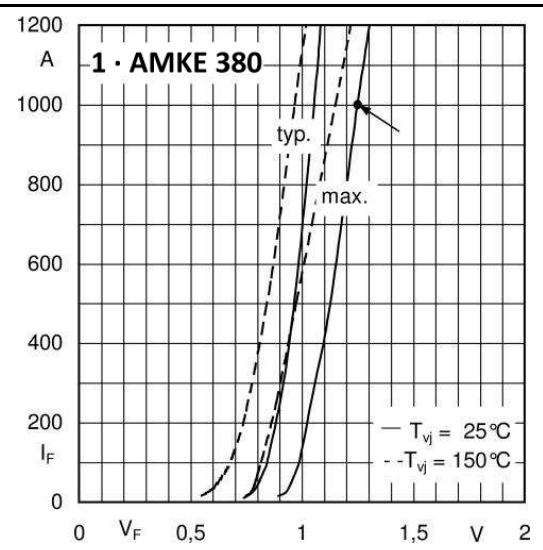


Fig. 15 Forward characteristics

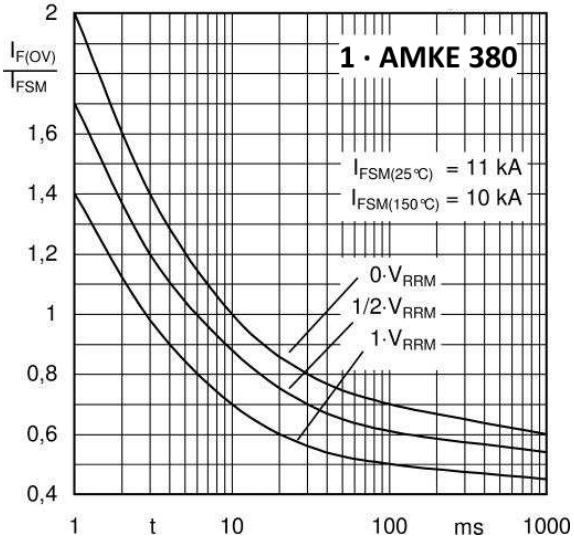
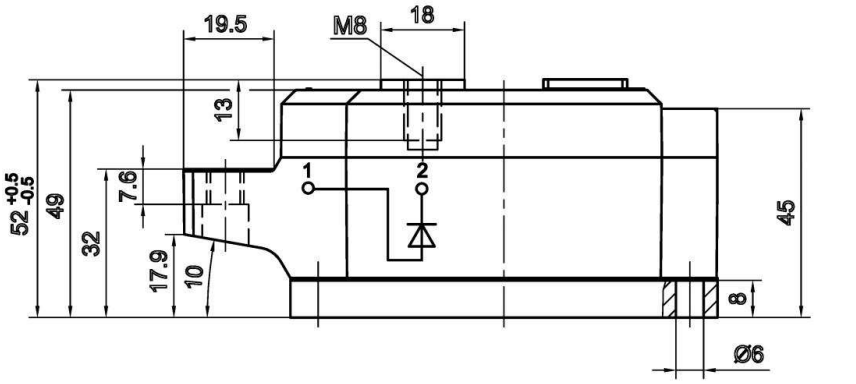
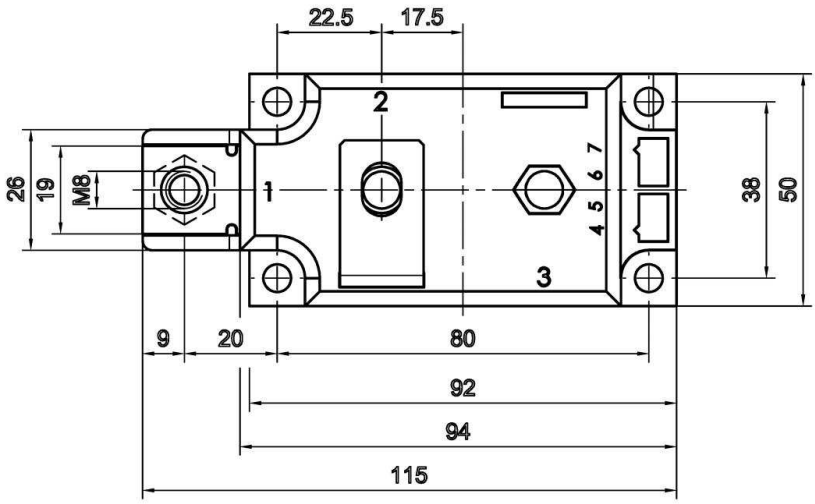


Fig. 16 Surge overload current vs. time

DIMENSIONS





Dimensions in mm

TOPOLOGY OF INTERNAL CONNECTION